

Support Information

3d Transition Metal Coordination on Monolayer MoS₂: A facile doping method to functionalize surfaces

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Table S1: Calculated adsorption energy (E_{ads}), M-Mo distance and M-S bond length for first row transition metal coordination on surface

Element	e Config	E_{ads} (eV)	M-Mo (\AA)	M-S (\AA)
Sc	$3d^14s^2$	-2.74	3.32	2.31
Ti	$3d^24s^2$	-3.02	2.99	2.32
V	$3s^34s^2$	-2.88	2.84	2.28
Cr	$3d^54s^1$	-1.58	3.06	2.38
Mn	$3d^54s^2$	-1.41	2.96	2.35
Fe	$3d^64s^2$	-2.64	2.52	2.13
Co	$3d^74s^2$	-3.05	2.85	2.06
Ni	$3d^84s^2$	-3.85	2.58	2.13
Cu	$3d^{10}4s^1$	-1.73	2.83	2.25
Zn	$3d^{10}4s^2$	-0.40	4.13	3.16

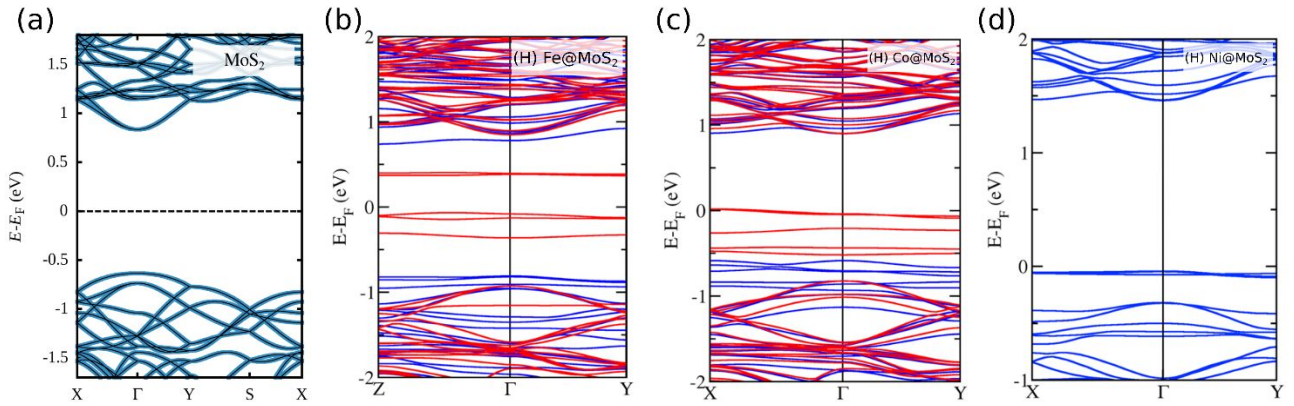


Figure S1: Electronic Band Dispersion of MoS₂ (a) and Fe (b), Co (c) and Ni (d) functionalization on H site. The blue and red curves indicate states with different spin polarization.

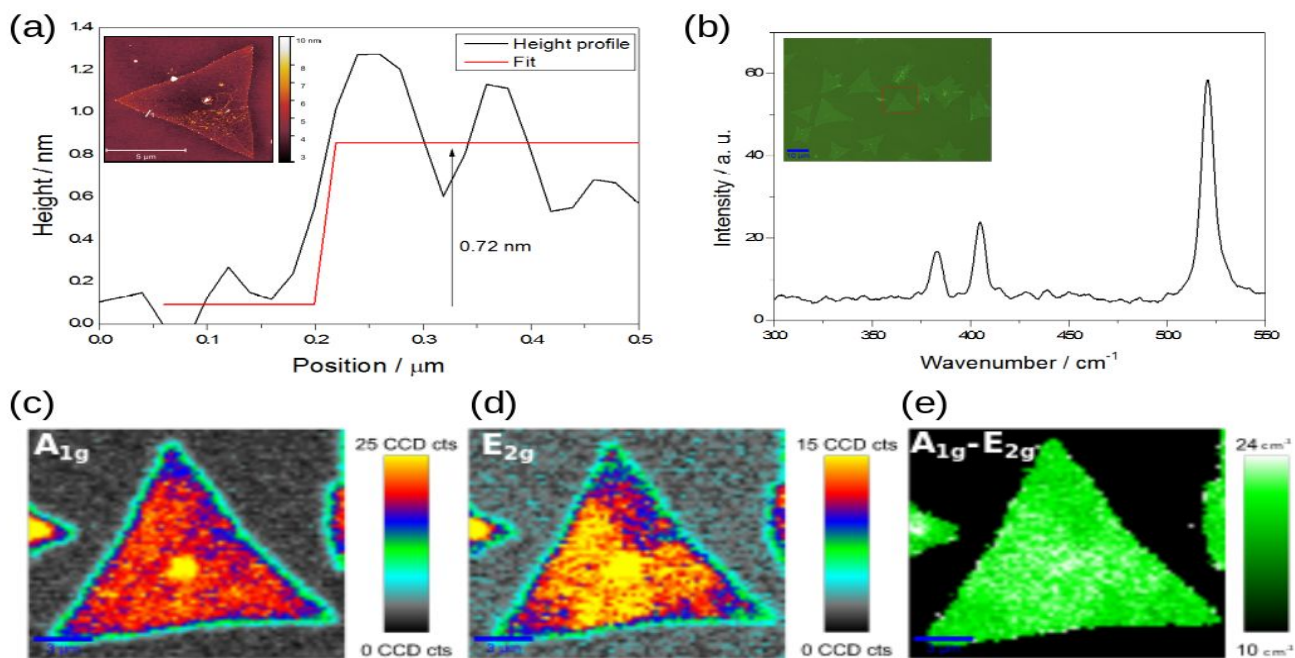


Figure S2: AFM image and height profile for MoS₂-Ni samples (a). Optical microscopy of MoS₂-Ni samples on inset (a,b). Raman spectra (b) and Raman mapping showing the A_{1g} (c) and E_{2g} (d) peaks intensity, and A_{1g} and E_{2g} wavenumber difference of MoS₂-Ni samples (e).

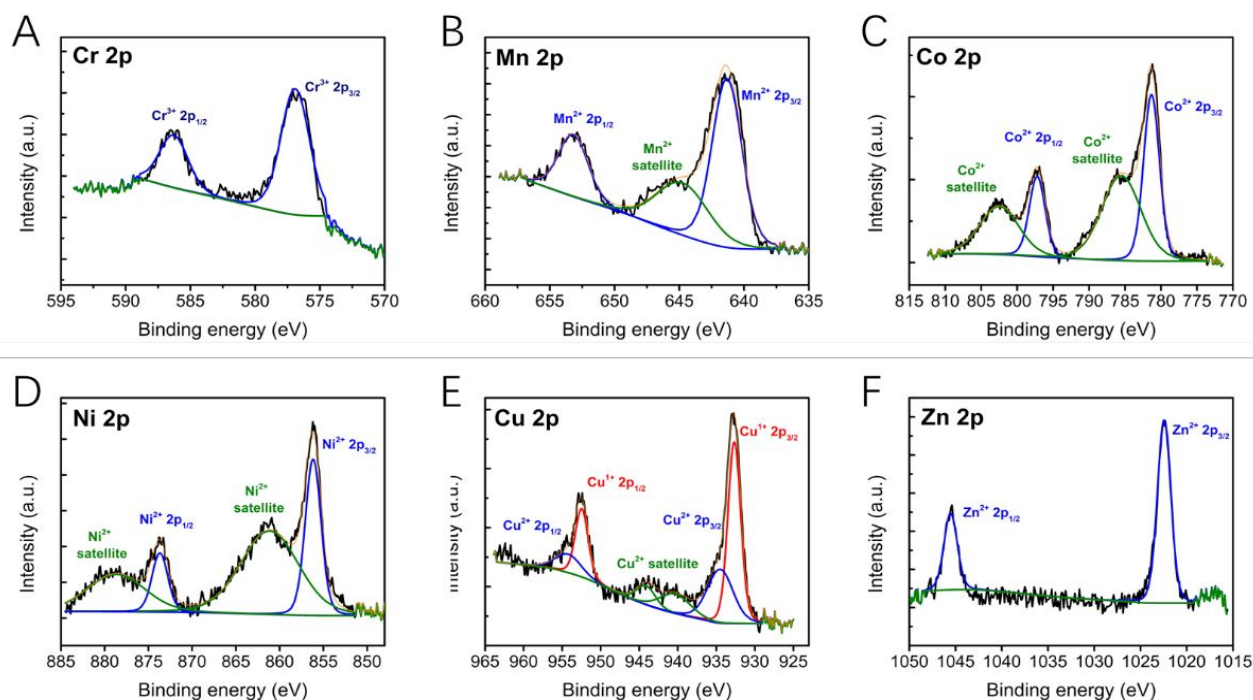


Figure S3: XPS spectra of TM 3d orbit after functionalization. (A) Cr 2p orbit of Cr-MoS₂. The black curve is the original spectra after C1scalibaration. The blue curves are fitted to Cr³⁺ 2p_{1/2} and 2p_{3/2} peaks and they match perfectly with the original spectra. (B) Mn 2p orbit of Mn-MoS₂. The blue curves show the fitted Mn²⁺ peaks. In addition to the fitted Mn 2p_{1/2} and 2p_{3/2} peaks, a Mn satellite peak is also visible in the green curve. (C) and (D) Co and Ni 2p orbit of Co-MoS₂ and Ni-MoS₂. Similar satellite peaks could be fitted in addition to the Co²⁺ and Ni²⁺ peaks. (E) Cu 2p orbit of Cu-MOS₂. Here the spectra are fitted into 3 groups. The Cu¹⁺ 2p peaks in red, the Cu²⁺ 2p peaks in blue and the Cu²⁺ satellite peaks in green. The presence of the Cu¹⁺ peaks indicate a reduction reaction between the Cu²⁺ precursor and MoS₂. Similar to that of Au and MoS₂. (F) Zn 2p orbit of Zn-MoS₂ showing a perfect fit of Zn²⁺ 2p_{1/2}, 2p_{3/2} and the original spectrum.

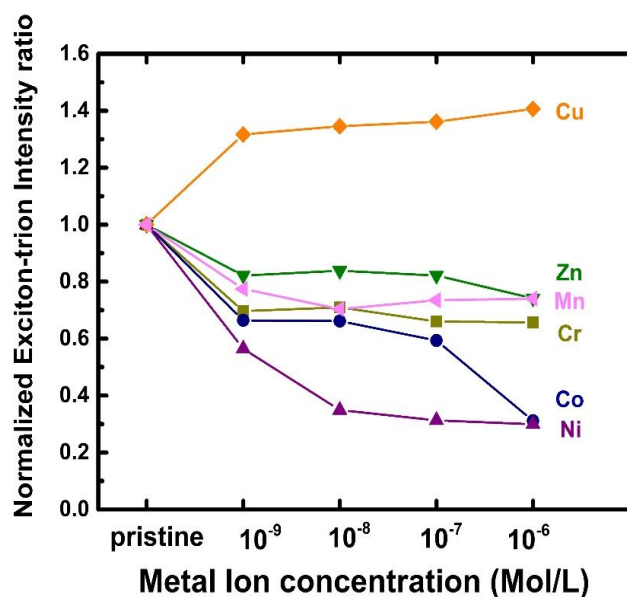


Figure S4: Normalized exciton to trion intensity changes showing the percent change in exciton to trion ratio for various TM functionalized MoS₂ samples at different TM concentrations. The TMs here can be separated into 3 groups. One is Cu, which is showing an increase to the exciton to trion ratio, indicating p-type doping on the MoS₂. The second group is Zn, Mn and Cr where we see a small decrease in the ratio, indicating weak n-type doping of MoS₂. The last group is Co and Ni where we see a large decrease in the ratio that corresponds to strong n-type doping of MoS₂.

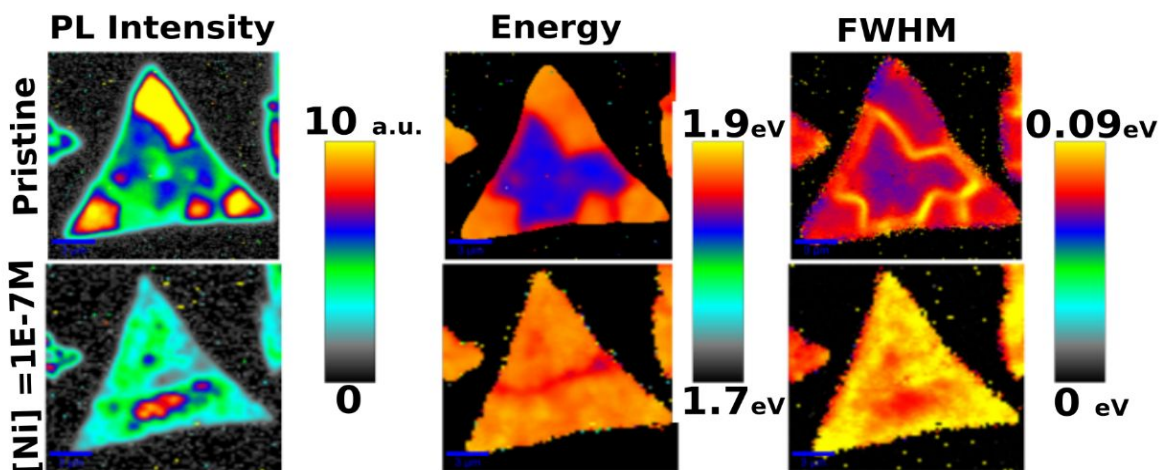


Figure S5: Photoluminescence mapping showing the PL intensity, energy of the maximum intensity, and the peak full width at half maximum (FWHM) of Pristine and Ni functionalized MoS₂. Intensity changes are uniform through the whole flake, thus indicating homogenous dispersion onto the flake's surface.

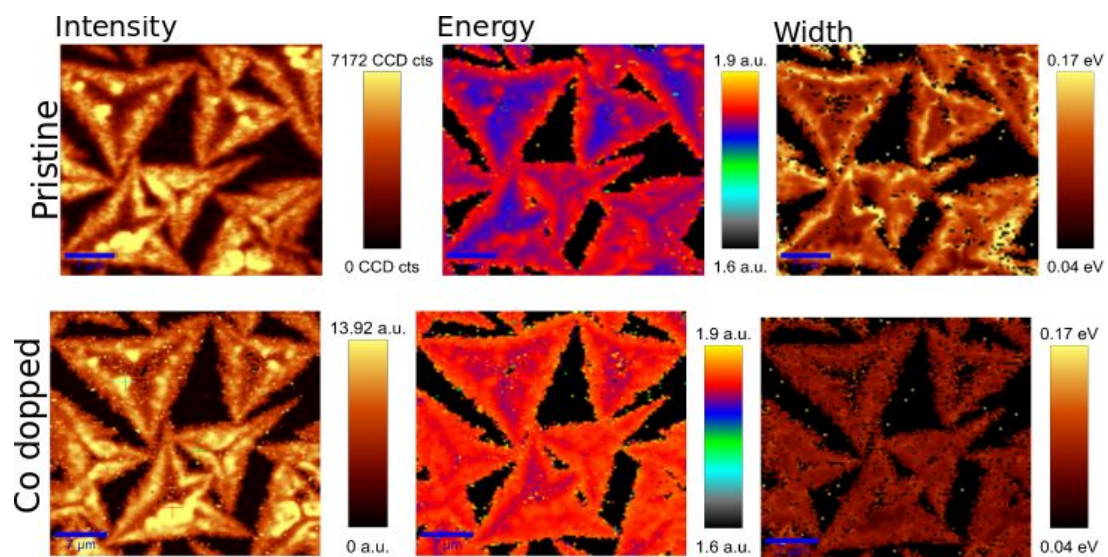


Figure S6: Photoluminescence mapping showing the PL intensity, energy of the maximum intensity, and the peak full width at half maximum (FWHM) of Pristine and Co functionalized MoS₂. Intensity changes are uniform through the whole flake, thus indicating homogenous dispersion onto the flake's surface.

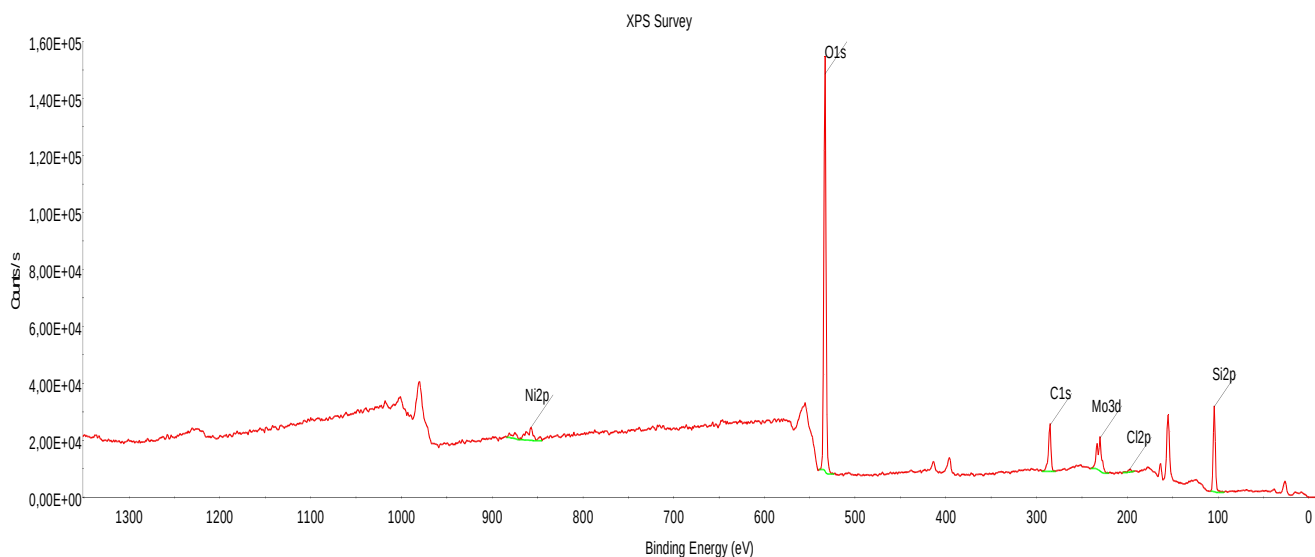


Figure S 7: Survey XPS spectra of $\text{MoS}_2\text{-NiCl}_3$ samples showing the presence of MoS_2 (Mo 3d and S 2p peaks), Ni (2p peak), and Cl (2p peak).

Table S2: Atomic percentage calculated from the $\text{MoS}_2\text{-NiCl}_3$ XPS survey spectra.

Name	Peak BE	FWHM eV	Area (P) CPS.eV	Atomic %
O1s	533.11	2.81	407121.28	49.32
Si2p	104.03	2.82	83899.53	29.76
C1s	285.22	2.9	54949.48	17.17
Mo3d	230.12	3.33	65903.51	2.12
Ni2p	857.04	3.56	55668.4	1.13
Cl2p	197.49	3.71	3831.59	0.5

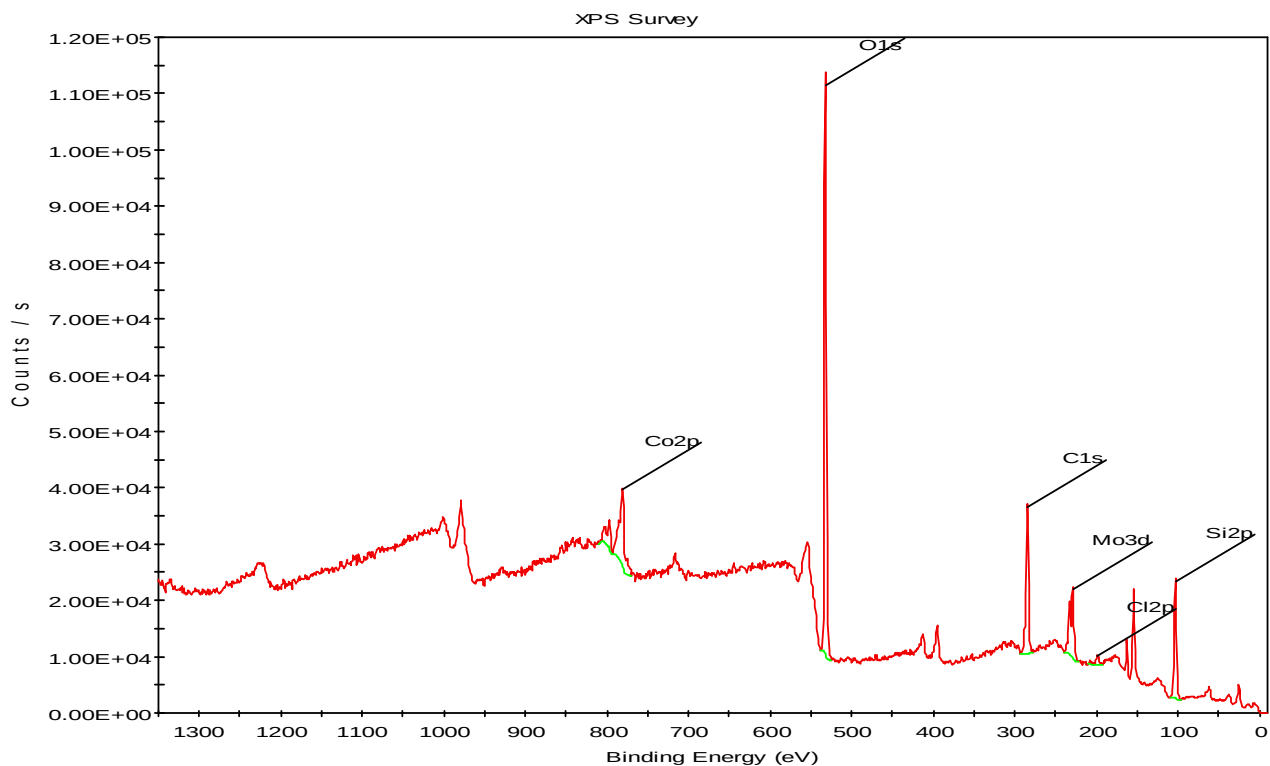


Figure S8: Survey XPS spectra of $\text{MoS}_2\text{-CoCl}_3$ samples showing the presence of MoS_2 (Mo 3d and S 2p peaks), Co (2p peak), and Cl (2p peak).

Table S3: Atomic percentage calculated from the $\text{MoS}_2\text{-CoCl}_3$ XPS survey spectra.

Name	Peak BE	FWHM eV	Area (P) CPS.eV	Atomic %
O1s	532.1	3.002	315827.46	39.95
Si2p	103.09	2.937	63121.09	23.38
C1s	284.31	2.832	91342.13	29.79
Co2p	781.22	4.925	139550.87	3.21
Mo3d	229.21	3.207	72065.21	2.42
Cl2p	198.29	4.266	9115.36	1.25

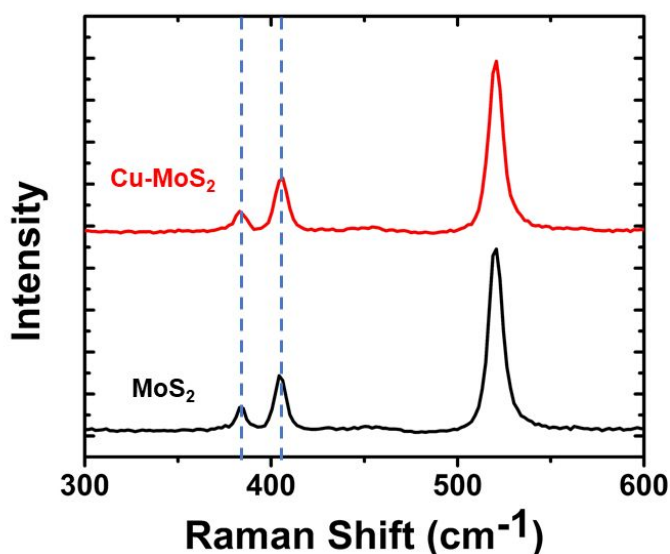


Figure S9: Raman Spectra of pristine and Cu functionalized MoS₂. The MoS₂ signature peaks do not change in wavenumber or intensity after Cu functionalization, indicating the functionalization process do not alter the intrinsic structure of the MoS₂ lattice.

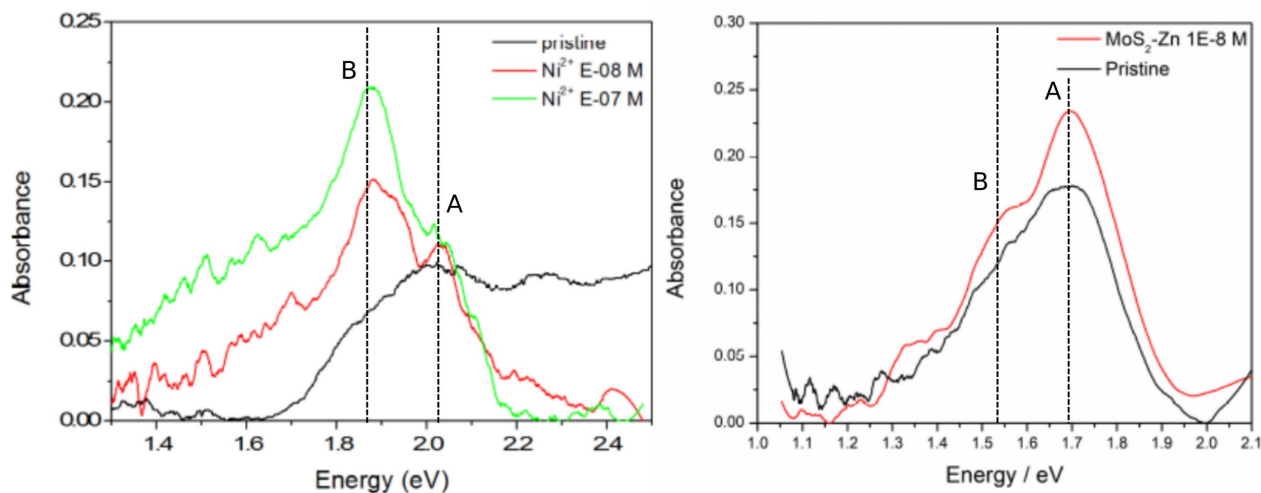


Figure S10: Room temperature absorbance spectra of the Ni-MoS₂ (right) and of Zn-MoS₂ (left) samples. A slight blue shift of the A and B excitons and new features associated with charge transfer transitions at energies lower than 1.6eV, are observed in the Ni-MoS₂ samples, as expected from the electronic band structure for the complex in Figure 2 of the main text.

Reflectance spectra were collected with a 400-2400 nm supercontinuum laser source (NKT Photonics), focused through a Nikon TU Plan Fluor EPI 50x objective (NA 0.8). Signal was collected with a

Yokogawa Optical Spectrum Analyzer (OSA), with sensitivity ranging from 350-1200 nm. The reflected light was measured as-grown on SiO₂(300nm)/Si substrates, with an identical, clean substrate used for the calculation of reflectance through the relationship $Reflectance = I_{sample}/I_{substrate}$. Absorbance was calculated from reflectance using the relationship $Absorbance = -\ln(10) * \ln(Reflectance)$.

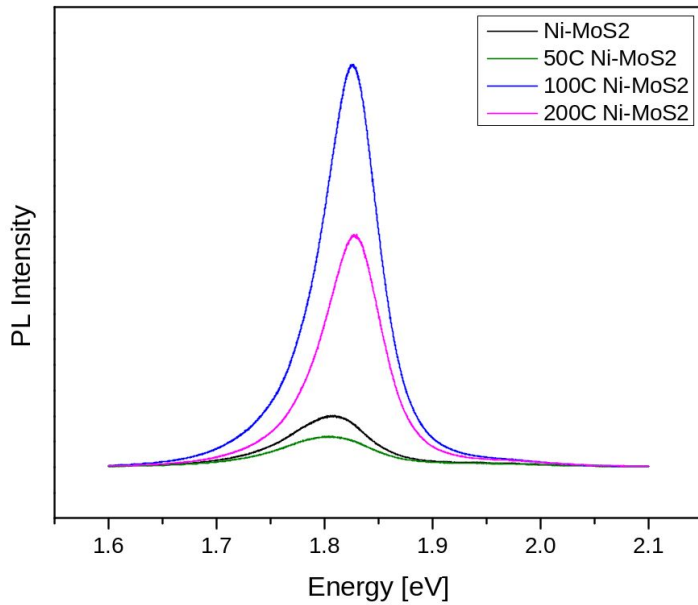


Figure S11: Photoluminescence spectrum of Ni functionalized MoS₂ monolayers at room temperature (black curve) and annealed at 50 °C (green curve), 100 °C (blue curve) and 200 °C (pink curve). Ni-MoS₂ samples at room temperature and annealed at 50 °C show excitation/trion ratio close to 0.4 and FWHM of 320 meV. Ni-MoS₂ annealed at 100 and 200 °C show excitation/trion ratio close to 1.6 and FWHM of 280 meV, similar to the pristine MoS₂.

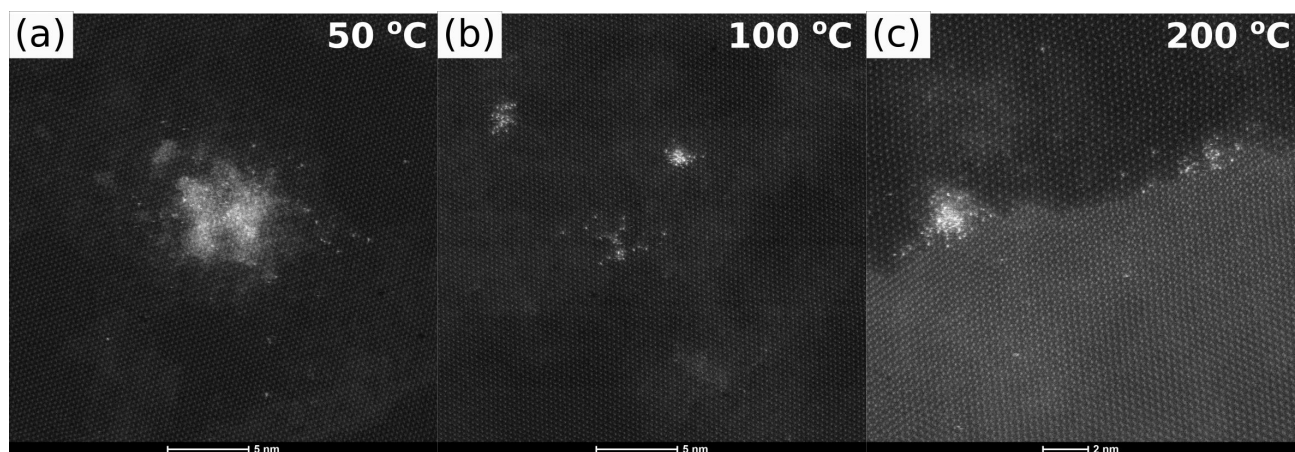


Figure S12: HAADF-STEM images of MoS₂-Ni samples annealed at 50 °C (a), 100 °C (b) and 200 °C (c), where the bright spots show Ni single atoms atomically dispersed on the MoS₂ basal plane and some clustering can be seen.